





N-CHANNEL ENHANCEMENT MODE MOSFET

Features

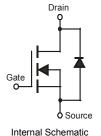
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

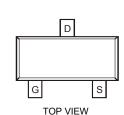
Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (approximate)









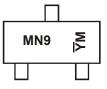
Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2041L-7	SOT-23	3000/Tape & Reel

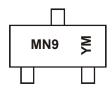
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information







Shanghai A/T Site

MN9 = Product Type Marking Code

YM = Date Code Marking for SAT (Shanghai Assembly/ Test site) YM = Date Code Marking for CAT (Chengdu Assembly/ Test site)

Y or \overline{Y} = Year (ex: A = 2013)

M = Month (ex: 9 = September)

Date Code Key

Date Code Noy												
Year	200	9	2010		2011	20	12	2013		2014	2	2015
Code	W		X		Υ	2	7	Α		В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characte	eristic		Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage		V _{GSS}	±12	V	
Continuous Drain Current (Note 5) Steady $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$		I _D	6.4 4.5	А	
Pulsed Drain Current (Note 6)			I _{DM}	30	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	0.78	W
Thermal Resistance, Junction to Ambient @ T _A = +25°C	$R_{\theta JA}$	161	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes:

- 5. Device mounted on FR-4 PCB with minimum recommended pad layout.
- 6. Repetitive rating, pulse width limited by junction temperature.

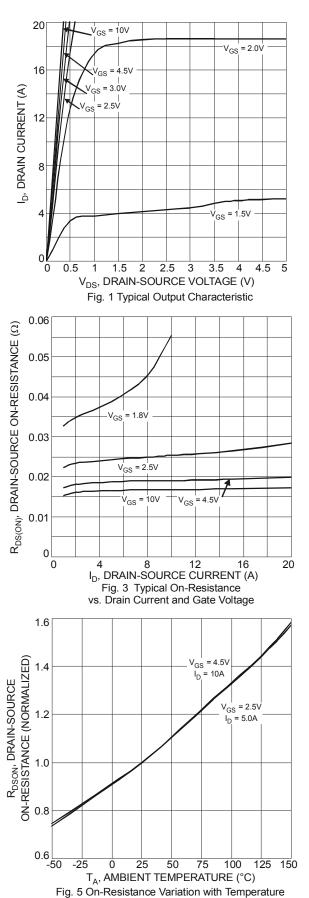
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 7)								
Drain-Source Breakdown Voltage	BV _{DSS}	20	_		V	$V_{GS} = 0V, I_D = 250\mu A$		
Zero Gate Voltage Drain Current T _J = 25°C	I _{DSS}		_	1.0	μΑ	V_{DS} = 20V, V_{GS} = 0V		
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	V _{GS} = ±12V, V _{DS} = 0V		
ON CHARACTERISTICS (Note 7)								
Gate Threshold Voltage	V _{GS(th)}	0.5	_	1.2	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$		
Static Drain-Source On-Resistance	0	_	20	28	mΩ	$V_{GS} = 4.5V$, $I_D = 6.0A$		
Static Dialii-Source Off-Resistance	R _{DS (ON)}		26	41	11122	$V_{GS} = 2.5V$, $I_D = 5.2A$		
Forward Transfer Admittance	Y _{fs}	_	6	_	S	V _{DS} = 10V, I _D = 6A		
Diode Forward Voltage	V_{SD}	_	0.7	1.2	V	V _{GS} = 0V, I _S = 1.7A		
DYNAMIC CHARACTERISTICS (Note 8)						_		
Input Capacitance	C _{iss}		550	-		V _{DS} = 10V, V _{GS} = 0V, f = 1.0MHz		
Output Capacitance	Coss	-	88	_	pF			
Reverse Transfer Capacitance	C _{rss}	_	81	_				
Gate Resistance	R_g	_	1.34	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$		
Total Gate Charge (10V)	Q_g	_	15.6	_	nC	$V_{GS} = 10V, V_{DS} = 10V, I_D = 6A$		
Total Gate Charge (4.5V)	Q_g	_	7.2	_		V _{GS} = 4.5V, V _{DS} = 10V, I _D = 6A		
Gate-Source Charge	Q_{gs}	_	1.0	_	nC			
Gate-Drain Charge	Q_{gd}	_	1.9	_				
Turn-On Delay Time	t _{D(on)}	_	4.69	_		V _{DD} = 10V, V _{GEN} = 4.5V,		
Turn-On Rise Time	t _r	_	13.19	_				
Turn-Off Delay Time	t _{D(off)}	_	22.10	_	ns	$R_{GEN} = 1\Omega$, $I_D = 6.7A$		
Turn-Off Fall Time	t _f	_	6.43	_				

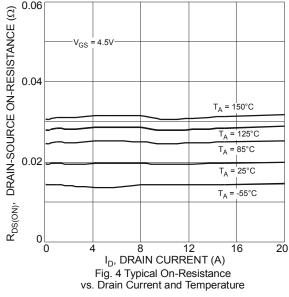
Notes:

- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to production testing.





20 V_{DS} = 5V 16 (V) LN 12 8 T_A = 150°C T_A = 25°C T_A = 35°C T_A = 35°C T_A = 35°C



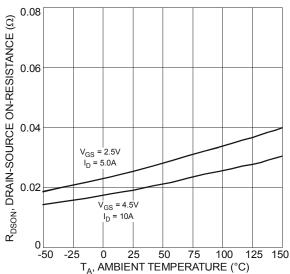
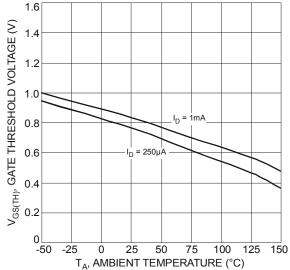
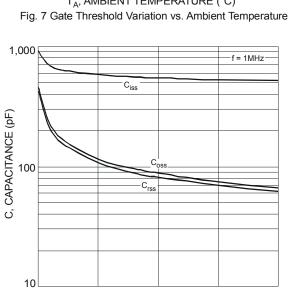


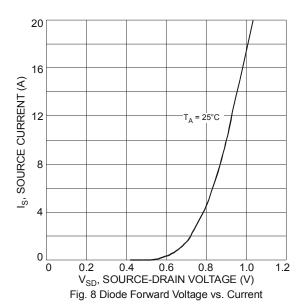
Fig. 6 On-Resistance Variation with Temperature







V_{DS}, DRAIN-SOURCE VOLTAGE (V) Fig. 9 Typical Total Capacitance



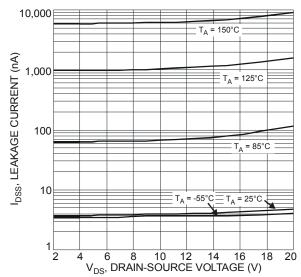
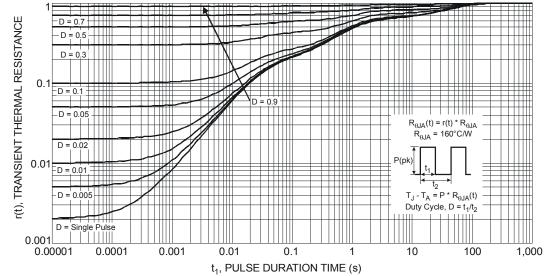


Fig. 10 Typical Leakage Current vs. Drain-Source Voltage



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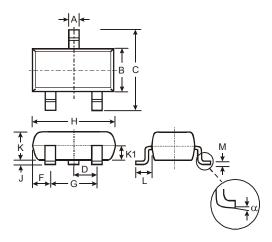
Fig. 11 Transient Thermal Response

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Package Outline Dimensions

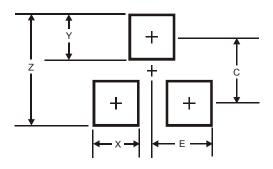
 $Please see AP02002 \ at \ http://www.diodes.com/datasheets/ap02002.pdf \ for \ the \ latest \ version.$



	SOT-23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.903	1.10	1.00					
K1	1	1	0.400					
L	0.45	0.61	0.55					
M	0.085	0.18	0.11					
α	0°	8°	-					
All	All Dimensions in mm							

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
Е	1.35



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